6.2mm (0.25INCH) FOUR DIGIT NUMERIC DISPLAY

Part Number: CA25-11EWA HIGH EFFICIENCY RED

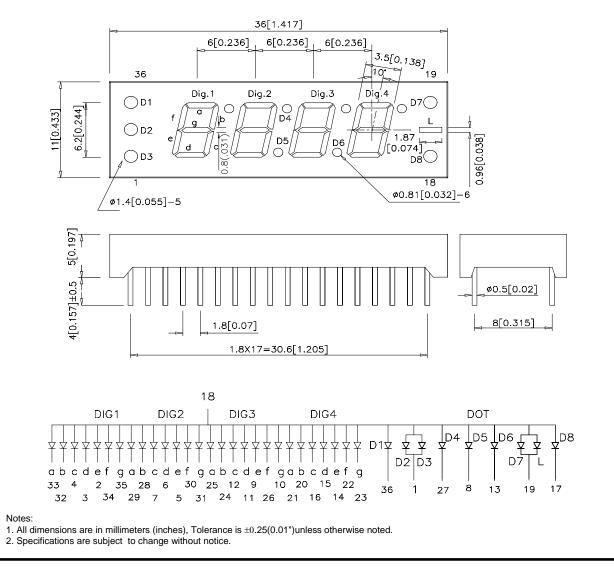
Features

- •0.25 INCH DIGIT HEIGHT
- •LOW CURRENT OPERATION.
- •EXCELLENT CHARACTER APPEARANCE.
- •EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- •I.C. COMPATIBLE.
- •CATEGORIZED FOR LUMINOUS INTENSITY.
- •MECHANICALLY RUGGED.
- •STANDARD : GRAY FACE, WHITE SEGMENT.
- •RoHS COMPLIANT.

Description

The High Efficiency Red source color devices are made With Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



SPEC NO: DSAB7148 APPROVED: J. Lu REV NO: V.7 CHECKED: Joe Lee DATE: AUG/01/2006 DRAWN: W.J.ZHU PAGE: 1 OF 4 ERP:1304000028

Selection Guide

Part No.	Dice	Lens Type	lv (ucd) [1] @ 10mA		Description	
			Min.	Тур.	-	
CA25-11EWA	HIGH EFFICIENCY RED (GaAsP/GaP)	WHITE DIFFUSED	1200	6400	Common Anode	

Note:

1.Luminous Intensity / Luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	High Efficiency Red	627		nm	I⊧=20mA
λD [1]	Dominant Wavelength	High Efficiency Red	625		nm	I⊧=20mA
Δλ1/2	Spectral Line Half-width	High Efficiency Red	45		nm	IF=20mA
С	Capacitance (Per Segment)	High Efficiency Red	15		pF	VF=0V;f=1MHz
Vf [2]	Forward Voltage (Per Segment)	High Efficiency Red	2.0	2.5	V	IF=20mA
lr	Reverse Current (Per Segment)	High Efficiency Red		10	uA	VR = 5V

Notes:

1.Wavelength: +/-1nm

2.Forward Voltage: +/-0.1V

Absolute Maximum Ratings at TA=25°C

Parameter	High Efficiency Red	Units		
Power dissipation (Per Segment)	105	mW		
DC Forward Current (Per Segment)	30	mA		
Peak Forward Current [1] (Per Segment)	160	mA		
Reverse Voltage (Per Segment)	5	V		
Operating/Storage Temperature	-40°C To +85°C			
Lead Solder Temperature [2]	260°C For 5 Seconds			

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.

